

Monolithic Digital IC

LB11996,11996H

Three-Phase Brushless Motor Driver for CD-ROM Spindle Motor Driver

Preliminary

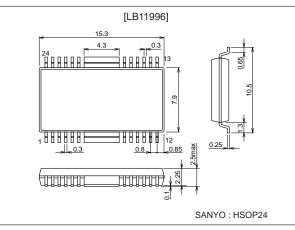
Features

- Current linear drive
- Control V type amplifier
- Separate power supply for output upper side bias circuit allows low output saturation by boosting this power supply only (useful for 5V power supply types).
- Upper side current detection technique loses loss voltage of current detection resistor. Voltage drop caused by this resistor reduces internal power dissipation of IC.
- Built-in short braking circuit
- · Built-in reverse blocking circuit
- Hall FG output
- Built-in S/S function
- Built-in current limiter circuit
- Built-in Hall power supply
- Built-in thermal shutdown circuit
- 1 Hall FG/3 Hall FG switchable
- Supports 3.3V DSP

Package Dimensions

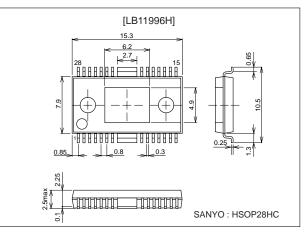
unit: mm

3227-HSOP24



unit: mm

3234-HSOP28HC



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Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol		Conditions	Ratings	Unit
Maximum power supply voltage 1	V _{CC} 1 max			7.0	V
Maximum power supply voltage 2	V _{CC} 2 max			14.4	V
Maximum power supply voltage 3	V _{CC} 3 max			14.4	V
Maximum applied output voltage	Vo max			14.4	V
Maximum applied intput voltage	Vi max			V _{CC} 1	V
Maximum output current	lo max			1.3	А
Allowable power dissipation	Pd max	[LB11996]	IC only	0.79	W
			*With specified substrate	*1.8	
		[LB11996H]	IC only	0.8	
			*With specified substrate	*1.9	
Operating temperature	Topr			–20 to +75	°C
Storage temperature	Tstg			–55 to +150	°C

* Specified substrate: $114.3 \times 76.1 \times 1.6 \text{ mm}^3$ glass epoxy

Allowable Operating Ranges at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Power supply voltage 1	V _{CC} 1		4 to 6	V
Power supply voltage 2	V _{CC} 2	≥V _{CC} 1	4 to 13.6	V
Power supply voltage 3	V _{CC} 3		4 to 13.6	V

Sample Application at Ta = $25^{\circ}C$

(1) 12V type

Power supply pin	Conditions	Ratings	Unit
V _{CC} 1	Regulated voltage	4 to 6	V
$V_{CC}2 = V_{CC}3$	Unregulated voltage	4 to 13.6	V

(2) 5V type

Power supply pin	Conditions	Ratings	Unit
$V_{CC}1 = V_{CC}3$	Regulated voltage	4 to 6	V
V _{CC} 2	Boost-up voltage or regulated voltage (Note)	4 to 13.6	V

Note: When boost-up voltage is used at V_{CC}^2 , output can be set to low-saturation.

$\label{eq:constraint} \mbox{Electrical Characteristics at Ta} = 25^{\circ}C, \ V_{CC}1 = 5V, \ V_{CC}2 = V_{CC}3 = 12V \ (unless \ otherwise \ specified)$

		$\begin{array}{c} C, V_{CC} = 3V, V_{CC} = V_{CC} = 12V \text{ (III)} \\ \hline \\ Conditions \end{array}$		Ratings		Linit
Parameter	Symbol	Conditions	min	typ	max	Unit
[Power supply current]						
Power supply current 1	V _{CC} 1	$V_{C} = V_{CREF}$		8		mA
Power supply current 2	V _{CC} 2	$V_{C} = V_{CREF}$		0		mA
Power supply current 3	V _{CC} 3	$V_{C} = V_{CREF}$		150	250	μΑ
Output idle current 1	I _{CC} 10Q	$V_{S/S} = 0V$			200	μΑ
Output idle current 2	I _{CC} 2OQ	$V_{S/S} = 0V$			30	μΑ
Output idle current 3	I _{CC} 3OQ	$V_{S/S} = 0V$			30	μΑ
[Output]	•					
Saturation voltage, upper side 1	V _{OU} 1	$I_0 = -0.5A, V_{CC}1 = 5V, V_{CC}2 = V_{CC}3 = 12V$		1.0		V
Saturation voltage, lower side 1	V _{OD} 1	$I_0 = 0.5A, V_{CC}1 = 5V, V_{CC}2 = V_{CC}3 = 12V$		0.3		V
Saturation voltage, upper side 2	V _{OU} 2	$I_{O} = -0.5A, V_{CC}1 = V_{CC}3 = 5V, V_{CC}2 = 12V$		0.3		V
Saturation voltage, lower side 2	V _{OD} 2	$I_{O} = 0.5A, V_{CC}1 = V_{CC}3 = 5V, V_{CC}2 = 12V$		0.3		V
Current limiter setting voltage	V _{CL}	$R_{RF} = 0.33\Omega$		0.37		V
[Hall amplifier]		•				
Common mode input voltage range	V _{HCOM}		1.2		V _{CC} 1-1.0	V
Input bias current	V _{HIB}			1		μΑ
Minimum Hall input level	V _{HIN}		60			mVp-p
[S/S pin]	•	·				
High level voltage	V _{S/SH}		2.0		V _{CC} 1	V
Low level voltage	V _{S/SL}				0.7	V
Input current	I _{S/SI}	$V_{S/S} = 5V$			200	μΑ
Leakage current	I _{S/SL}	$V_{S/S} = 0V$	-30			μA
[Control]		•				
VC pin input current	I _{VC}	$V_{C} = V_{CREF} = 1.65V$			1	μΑ
VCREF pin input current	IV _{CREF}	VC = V _{CREF} = 1.65V			1	μΑ
Voltage gain	GV _{CC}	$\Delta V_{RF} / \Delta V_{C}$		0.35		times
Startup voltage	V _{CTH}	V _{CREF} = 1.65V	1.5		1.8	V
Startup voltage width	ΔV_{CTH}	V _{CREF} = 1.65V	50		150	mV
[Hall power supply]		•				
Hall power supply voltage	V _H	I _H = 5 mA		0.8		V
Allowable current	Ι _Η		20			mA
[Thermal shutdown]	•	•				
Operating temperature	T _{TSD}	(Target)	150	180	210	°C
Hysteresis	ΔT_{TSD}	(Target)		15		°C
[Short braking]						
Brake pin at High level	V _{BRH}		4		5	V
Brake pin at Low level	V _{BRL}		0		1	V
[1 Hall FG/3 Hall FG select]						
FGSEL pin at High level	V _{FSH}		4		5	V
FGSEL pin at Low level	V _{FSL}		0		1	V

Note:

• During S/S OFF (standby), the Hall comparator is at High.

• Items shown to be "Target" are not measured.

Truth Table

$\overline{\ }$	Source		Input	Control	
	Sink	U	V	W	V _C
1	Phase W -> Phase V	ц		L	Н
I	Phase V -> Phase W			-	L
2	Phase W -> Phase U	н	1	L	Н
2	Phase U -> Phase W	HL	L	L	
3	Phase V -> Phase W	1	1	н	Н
5	Phase W -> Phase V	-	-		L
4	Phase U -> Phase V	> Phase V		L	Н
4	Phase V -> Phase U	-	H H H L	-	L
5	Phase V -> Phase U	н		н	Н
5	Phase U -> Phase V		L		L
6	Phase U -> Phase W	1	Ц	н	Н
U	Phase W -> Phase U	-	L		L

Input:

H: Input 1 is higher in potential than input 2 by at least 0.2V.

L: Input 1 is lower in potential than input 2 by at least 0.2V.

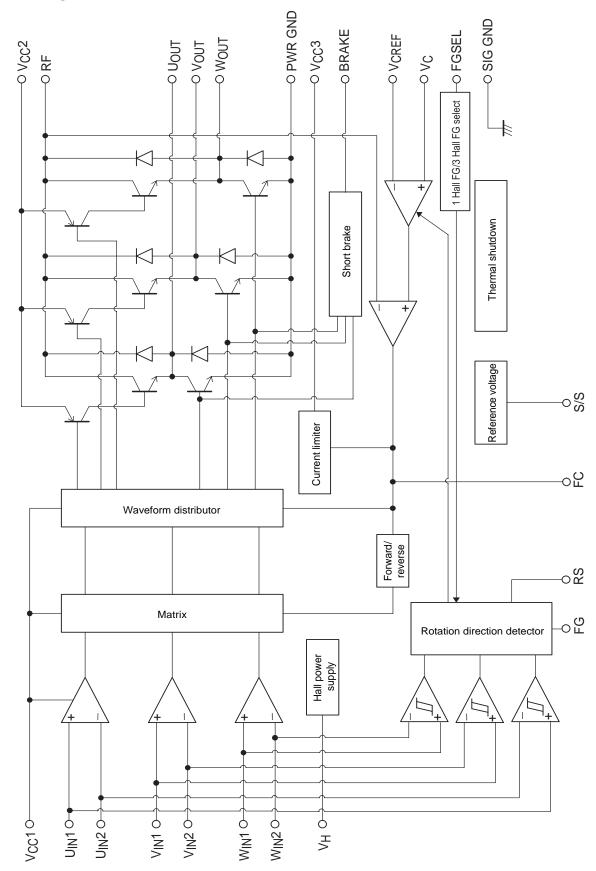
Brake Operation

Brake pin	Operation	
Н	Brake operation	
L	Normal rotation	

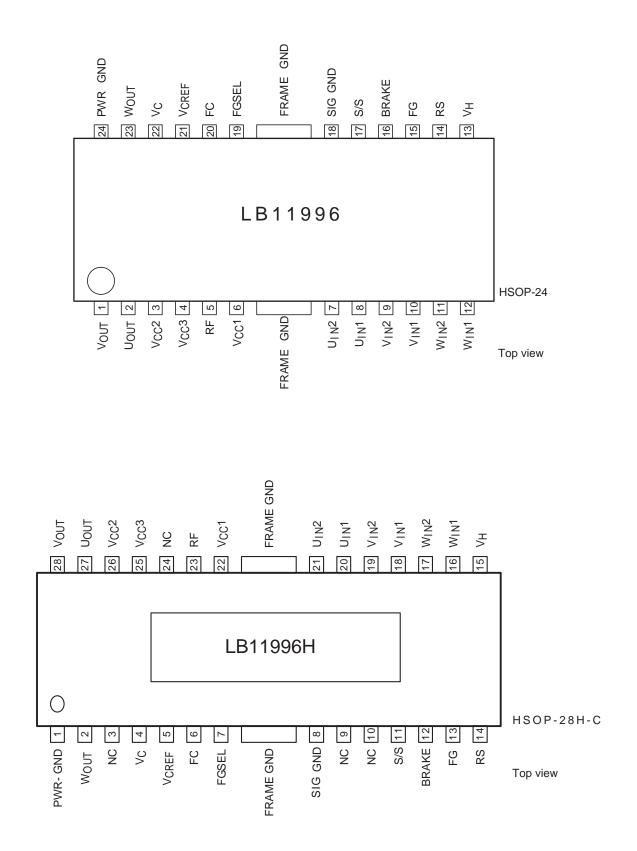
FGSEL (1 Hall /3 Hall select)

FGSEL	FG output principle	
Н	3 Hall FG output	
L	1 Hall FG output	

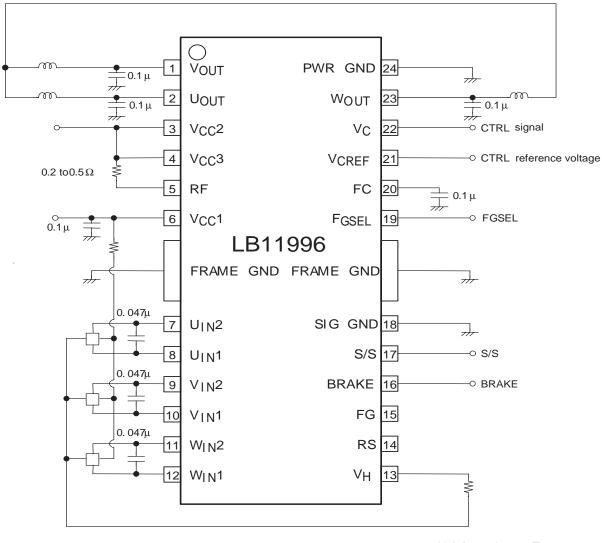
Block Diagram



Pin Assignments



Sample Application Circuit



Unit (capacitance: F)

Power supply - GND Output - GND Between Hall inputs Capacitor requirements may change depending on motor. For some motors, capacitor between Hall inputs may not be needed.

Pin number	Pin name	Pin voltage	Equivalent circuit	Pin function
3 (26)	V _{CC} 2	4V to 13.6V		Source side predrive voltage supply pin.
4 (25)	V _{CC} 3	4V to 13.6V		Constant current control amplifier voltage supply pin.
6 (22)	V _{CC} 1	4V to 6V		Power supply pin for all voltage except output transistors, source predrive, and constant current control amplifier.
14	RS		100μA Vcc1 100μA 114 15	Reverse detector pin Forward rotation: High Reverse rotation: Low
15 (13)	FG			1 Hall element waveform Schmitt comparator composite output
8 (20)	U _{IN} 1			U phase Hall element input and reverse detector U phase Schmitt
7 (21)	U _{IN} 2			comparator input pin. Logic High indicates U _{IN} 1 > U _{IN} 2.
10 (18)	V _{IN} 1	1.2V to		V phase Hall element input and reverse detector V phase Schmitt
9 (19)	V _{IN} 2	V _{CC} 1–1V	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	comparator input pin. Logic High indicates V _{IN} 1 > V _{IN} 2.
12 (16)	W _{IN} 1		· # # # . 18 · .	W phase Hall element input and reverse detector W phase Schmitt
11 (17)	W _{IN} 2		<u>16</u> <u>17</u>	comparator input pin. Logic High indicates W _{IN} 1 > W _{IN} 2.
13 (15)	V _H		75μA 30k 2k 2k 7/1/2 /// /// /// /// /// /// /// ///	Hall element lower side bias voltage supply pin.
17 (11)	S/S	0V to V _{CC} 1	(11)	When this pin is at 0.7V or lower, or when it is open, all circuits are inactive. When driving motor, set this pin to 2V or higher.

Pin Description (): LB11996H, other pins: identical

Continued on next page

Unit (resistance: Ω)

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Unit (resistance: \Omega)
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	rom preceding		Envirolant sincelt	Unit (resistance: Ω)
Pin number 18	Pin name	Pin voltage	Equivalent circuit	Pin function
(8)	SIG GND			GND pin for all circuits except output.
20 (6)	FC		V _{CC} 1 ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓	Control loop frequency compensator pin. Connecting a capacitor between this pin and GND prevents closed loop oscillation in current limiting circuitry.
21 (5)	V _{CREF}	0V to 3.5V	15μA 25μA 25μA 25μA 15μA	Control reference voltage applied pin Determines control start voltage.
22 (4)	v _c	0V to V _{CC} 1		Speed control voltage applied pin. V type control technique $V_C > V_{CREF}$: Forward $V_C < V_{CREF}$: Slowdown (Reverse-blocking circuit prevents reverse rotation.)
23 (2)	W _{OUT}			W-phase output.
24 (1)	PWR GND			Output transistor GND.
1 (28)	V _{OUT}			V-phase output.
2 (27)	U _{OUT}			U-phase output.
5 (23)	RF		$ \begin{array}{c} 3.9 \\ -3$	Upper side output NPN transistor collector pin (common for all 3 phases). For current detection, connect resistor between V_{CC} 3 pin and RF pin. Constant current control and current limiter works by detecting this voltage.
19 (7)	FGSEL		Vcc1 75k ↓ (19) 50k ↓ (7) 75k ↓ (7)	3 Hall FG/1 Hall FG select pin. FGSEL: High> 3 Hall FG Low/Open> 1 Hall FG
16 (12)	BRAKE		100μA 75k 100μA 75k 16 16 16 12)	Short brake pin. BRAKE: High> Brake Low/Open> Drive

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